

ABSOLUTE MAXIMUM RATINGS (Note 1)

Supply Voltage	75V	Operating Junction Temperature Range	
Switch Output Voltage	100V	LT1082M (OBSOLETE)	– 55°C to 150°C
Feedback Pin Voltage (Transient, 1ms)	±15V	LT1082I	– 40°C to 125°C
Storage Temperature Range	– 65°C to 150°C	LT1082C	0°C to 100°C
Lead Temperature (Soldering, 10 sec)	300°C		

PACKAGE/ORDER INFORMATION

TOP VIEW N8 PACKAGE 8-LEAD PLASTIC DIP $T_{JMAX} = 100^{\circ}C$, $\theta_{JA} = 90^{\circ}C/W$ (CN8) $T_{JMAX} = 125^{\circ}C$, $\theta_{JA} = 90^{\circ}C/W$ (IN8)	FRONT VIEW Q PACKAGE 5-LEAD DD $T_{JMAX} = 100^{\circ}C$, $\theta_{JA} = 40^{\circ}C/W$ (CQ) $T_{JMAX} = 125^{\circ}C$, $\theta_{JA} = 40^{\circ}C/W$ (IQ) NOTE: θ_{JA} VARIES FROM 25°C/W TO 50°C/W DEPENDING ON BOARD COMPOSITION.	FRONT VIEW T PACKAGE 5-LEAD T0-220 $T_{JMAX} = 100^{\circ}C$, $\theta_{JA} = 75^{\circ}C/W$, $\theta_{JC} = 8^{\circ}C/W$ (CT) $T_{JMAX} = 125^{\circ}C$, $\theta_{JA} = 75^{\circ}C/W$, $\theta_{JC} = 8^{\circ}C/W$ (IT)
ORDER PART NUMBER	ORDER PART NUMBER	ORDER PART NUMBER
LT1082CN8 LT1082IN8	LT1082CQ LT1082IQ	LT1082CT LT1082IT
J8 PACKAGE 8-LEAD CERAMIC DIP $T_{JMAX} = 150^{\circ}C$, $\theta_{JA} = 100^{\circ}C/W$ (MJ8) LT1082MJ8 OBSOLETE PACKAGE Consider the Q Package for Alternate Source		

Consult LTC Marketing for parts specified with wider operating temperature ranges.

ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^{\circ}C$. $V_{IN} = 15V$, $V_C = 0.5V$, $V_{FB} = V_{REF}$, output pin open, unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{REF}	Reference Voltage	Measured at Feedback Pin $V_C = 0.8V$	1.224	1.244	1.264	V
I_B	Feedback Input Current	$V_{FB} = V_{REF}$	●	350	750	nA
g_m	Error Amplifier Transconductance	$\Delta I_C = \pm 25\mu A$	●	2400	7000	μmho
	Error Amplifier Source or Sink Current	$V_C = 1.5V$	●	150	400	μA
	Error Amplifier Clamp Voltage	Hi Clamp, $V_{FB} = 1V$ Lo Clamp, $V_{FB} = 1.5V$	1.8	0.22	2.3	V
	Reference Voltage Line Regulation	$3V \leq V_{IN} \leq V_{MAX}$, $V_C = 0.8V$	●		0.03	%/V
A_V	Error Amplifier Voltage Gain	$0.9V \leq V_C \leq 1.4V$	350	650		V/V
	Minimum Input Voltage	●		2.6	3.0	V

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ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. $V_{IN} = 15\text{V}$, $V_C = 0.5\text{V}$, $V_{FB} = V_{REF}$, output pin open, unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
I_Q	Supply Current	$3\text{V} \leq V_{IN} \leq V_{MAX}$, $V_C = 0.6\text{V}$			4.5	7.0	mA
	Control Pin Threshold	Duty Cycle = 0	●	0.7 0.5	0.9	1.1 1.25	V V
	Normal/Flyback Threshold on Feedback Pin			0.58	0.67	0.8	V
f	Switching Frequency		●	50 45	60	70 75	kHz kHz
		$800\mu\text{A} \geq I_{FB} \geq 450\mu\text{A}$			12		kHz
BV	Output Switch Breakdown Voltage	$3\text{V} \leq V_{IN} \leq V_{MAX}$, $I_{SW} = 1.5\text{mA}$	●	100	115		V
	Control Voltage to Switch Current Transconductance				1.5		A/V
V_{FB}	Flyback Reference Voltage	$I_{FB} = 60\mu\text{A}$	●	17 16	18.6	20.5 21.5	V V
		$60\mu\text{A} \leq I_{FB} \leq 200\mu\text{A}$		3.5	4.6	6.5	V
	Flyback Reference Voltage Line Regulation	$I_{FB} = 60\mu\text{A}$, $3\text{V} \leq V_{IN} \leq V_{MAX}$			0.01	0.03	%/V
	Flyback Amplifier Transconductance (g_m)	$\Delta I_C = \pm 10\mu\text{A}$		150	300	500	μmho
	Flyback Amplifier Source and Sink Current	$V_C = 0.6\text{V}$ Source	●	15	32	70	μA
		$I_{FB} = 60\mu\text{A}$ Sink	●	30	50	90	μA
V_{SAT}	Output Switch "On" Resistance (Note 2)	$I_{SW} = 0.7\text{A}$ (LT1082C), $I_{SW} = 0.5\text{A}$ (LT1082M)	●		0.8	1.2	Ω
I_{LIM}	Switch Current Limit (LT1082C)	Duty Cycle = 20%	●	1.07		2.6	A
		Duty Cycle $\leq 50\%$	●	1.0		2.6	A
		Duty Cycle = 80% (Note 3)	●	0.8		2.4	A
	Switch Current Limit (LT1082I)	Duty Cycle = 20%	●	0.85		2.8	A
		Duty Cycle $\leq 50\%$	●	0.8		2.8	A
		Duty Cycle = 80% (Note 3)	●	0.65		2.6	A
	Switch Current Limit (LT1082M)	Duty Cycle = 20%	●	0.75		3.0	A
		Duty Cycle $\leq 50\%$	●	0.7		3.0	A
		Duty Cycle = 80% (Note 3)	●	0.6		2.8	A
ΔI_{IN}	Supply Current Increase During Switch-On Time				35	45	mA/A
ΔI_{SW}							
DC _{MAX}	Maximum Switch Duty Cycle			85	92	97	%
	Flyback Sense Delay Time				1.5		μs
	Shutdown Mode Supply Current	$3\text{V} \leq V_{IN} \leq V_{MAX}$, $V_C = 0.05\text{V}$			120	350	μA
	Shutdown Mode Threshold Voltage	$3\text{V} \leq V_{IN} \leq V_{MAX}$	●	70 50	150	250 300	mV mV

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

Note 2: Measured with V_C in hi clamp, $V_{FB} = 0.8\text{V}$.

Note 3: For duty cycles (DC) between 50% and 80%, minimum guaranteed switch current decreases linearly.

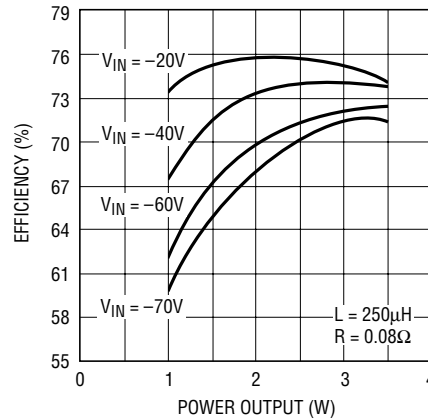
TYPICAL PERFORMANCE CHARACTERISTICS

Suggested Core Size and Inductance for Telecom 5V Supply

LOAD CURRENT	TYPE 52 POWDERED IRON	KOOL M μ OR MOLY-PERMALLOY
100mA	T38 250 μ H	T38 200 μ H
200mA	T50 250 μ H	T38 150 μ H
400mA	T60 250 μ H	T50 150 μ H
600mA	T60 250 μ H	T50 200 μ H
800mA	T80 350 μ H	T80 350 μ H

1082 GA

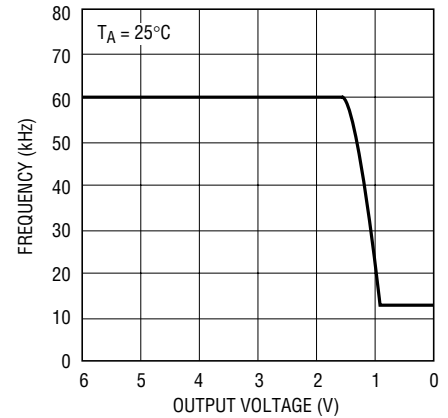
Telecom 5V Supply Efficiency



NOTE: THIS GRAPH IS BASED ON LOW CORE LOSS PERMALLOY INDUCTOR. IF POWDERED IRON CORE INDUCTOR IS USED, THE CORE LOSS IS TYPICALLY 100mW HIGHER.

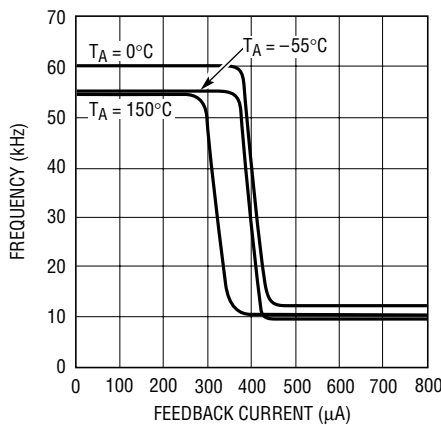
1082 G01

Telecom 5V Supply Short-Circuit Frequency Shift-Down



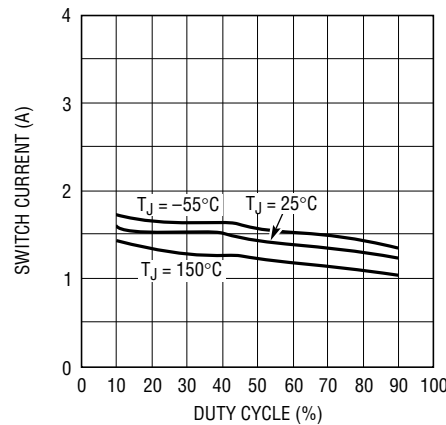
1082 G02

Short-Circuit Frequency Shift-Down vs Feedback Current



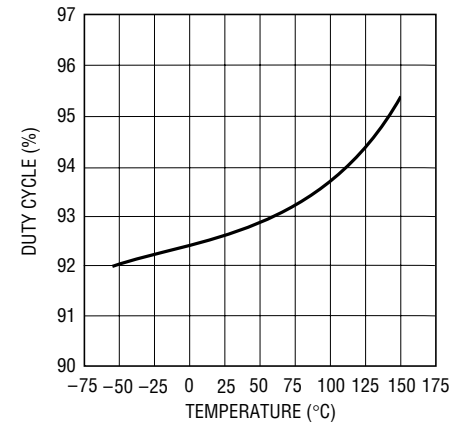
1082 G03

Switch Current Limit



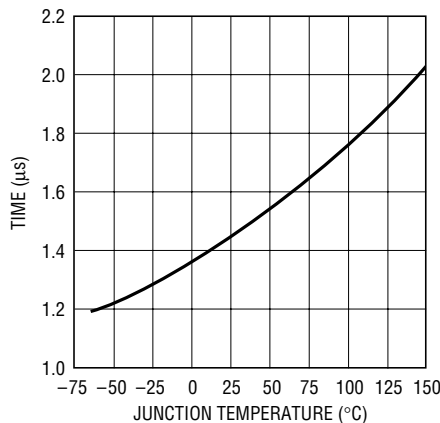
1082 G04

Maximum Duty Cycle



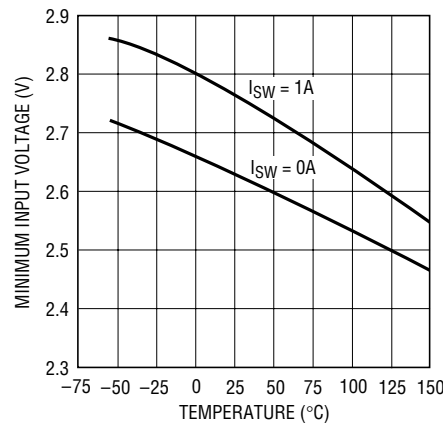
1082 G05

Flyback Blanking Time



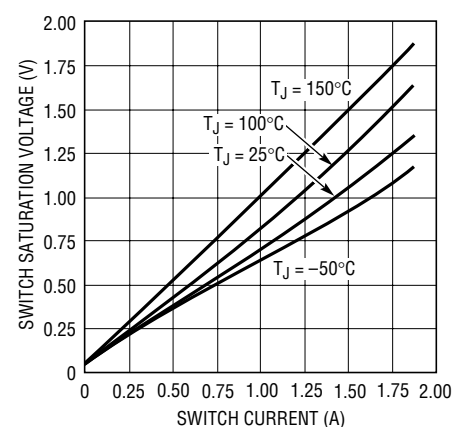
1082 G06

Minimum Input Voltage



1082 G07

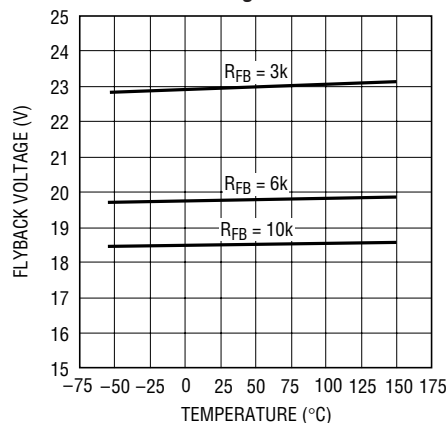
Switch Saturation Voltage



1082 G08
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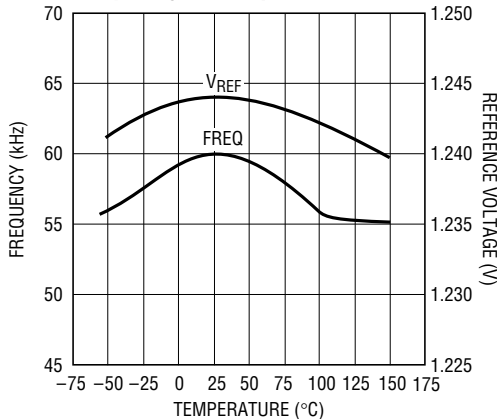
TYPICAL PERFORMANCE CHARACTERISTICS

Isolated Mode Flyback Reference Voltage



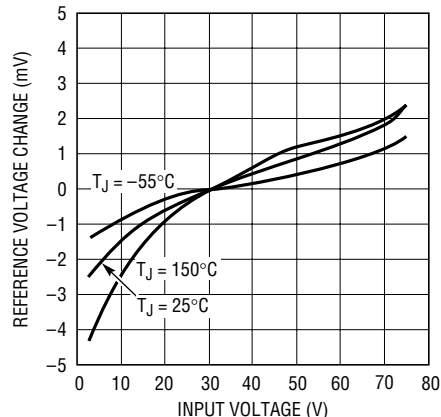
1082 G09

Reference Voltage and Switching Frequency vs Temperature



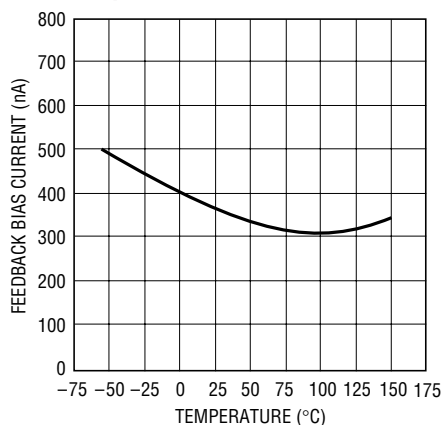
1082 G11

Line Regulation



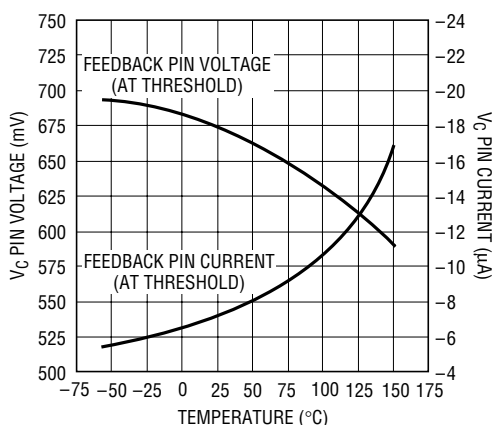
1082 G10

Feedback Bias Current vs Temperature



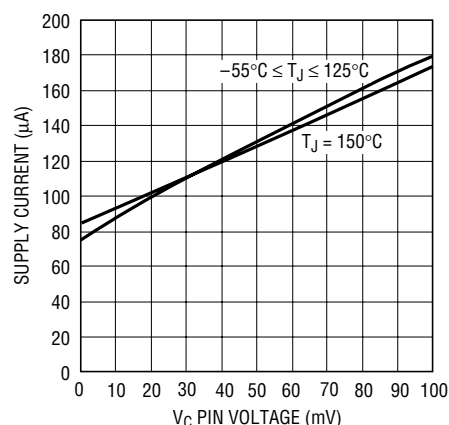
1082 G12

Normal/Feedback Mode Threshold on Feedback Pin



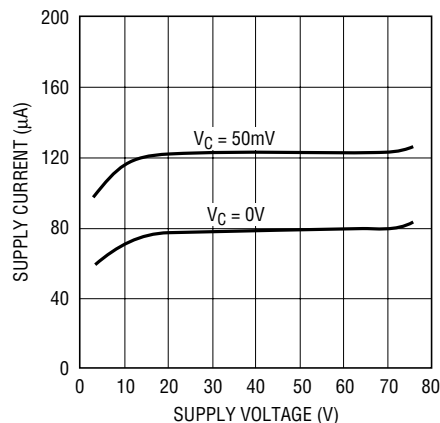
1082 G16

Shutdown Mode Supply Current



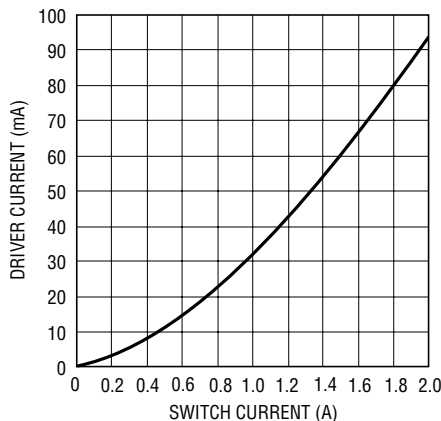
1082 G17

Supply Current vs Supply Voltage (Shutdown Mode)



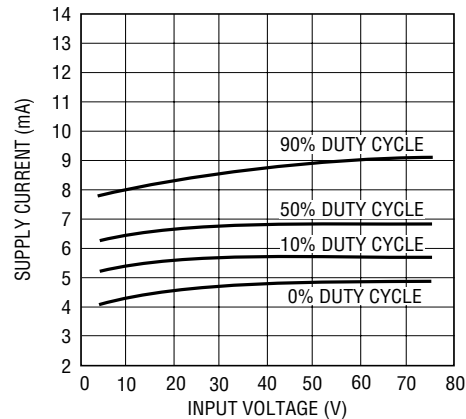
1082 G15

Driver Current* vs Switch Current



1082 G13

Supply Current vs Input Voltage**



1082 G14

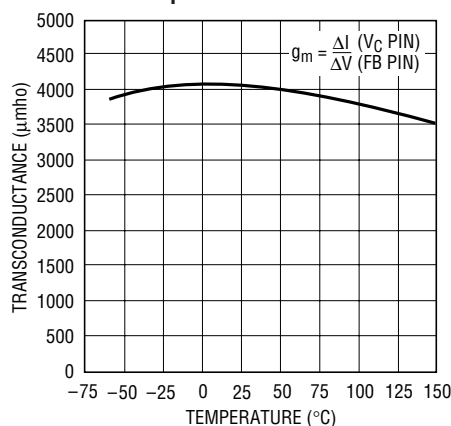
* AVERAGE SUPPLY CURRENT
 $= I_Q + DC(2.9 + 10^{-2} I_{SW} + 10^{-5} I_{SW}^2)$
 I_Q = QUIESCENT CURRENT, DC = DUTY CYCLE,
 I_{SW} = SWITCH CURRENT

** UNDER VERY LOW OUTPUT CURRENT CONDITIONS,
 DUTY CYCLE FOR MOST CIRCUITS WILL APPROACH
 10% OR LESS.

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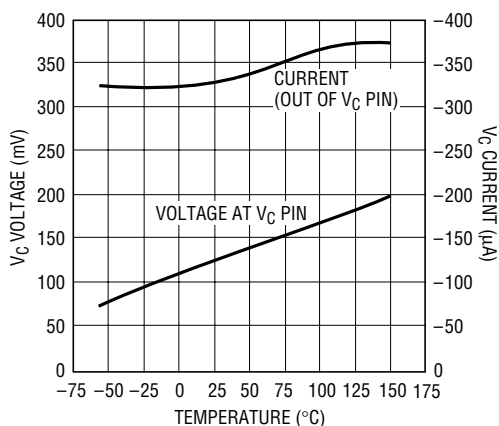
TYPICAL PERFORMANCE CHARACTERISTICS

Error Amplifier Transconductance



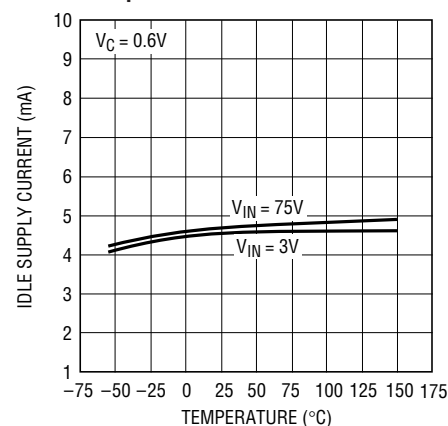
1082 G18

Shutdown Thresholds



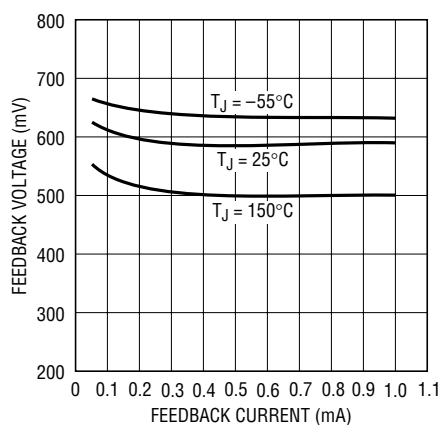
1082 G19

Idle Supply Current vs Temperature



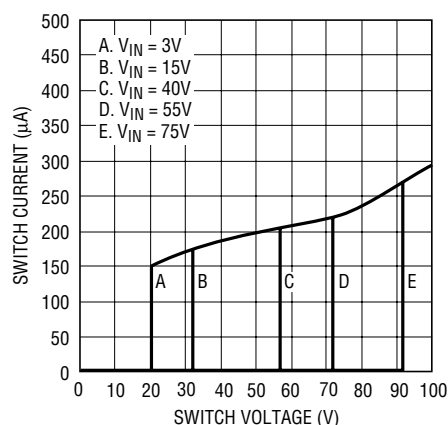
1082 G20

Feedback Pin Clamp Voltage



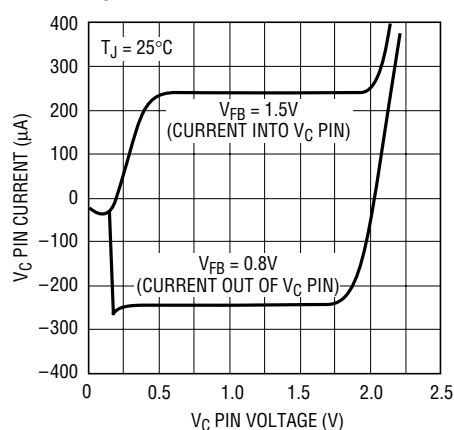
1082 G21

Switch "Off" Characteristics



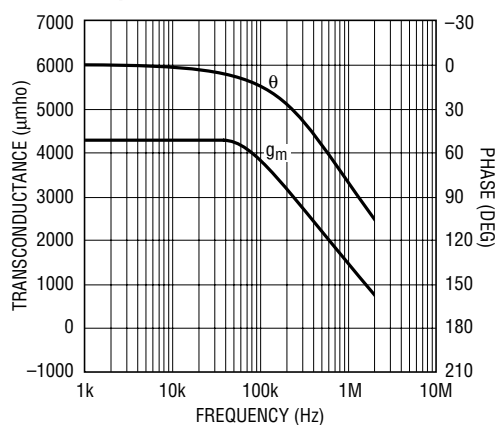
1082 G22

V_C Pin Characteristics



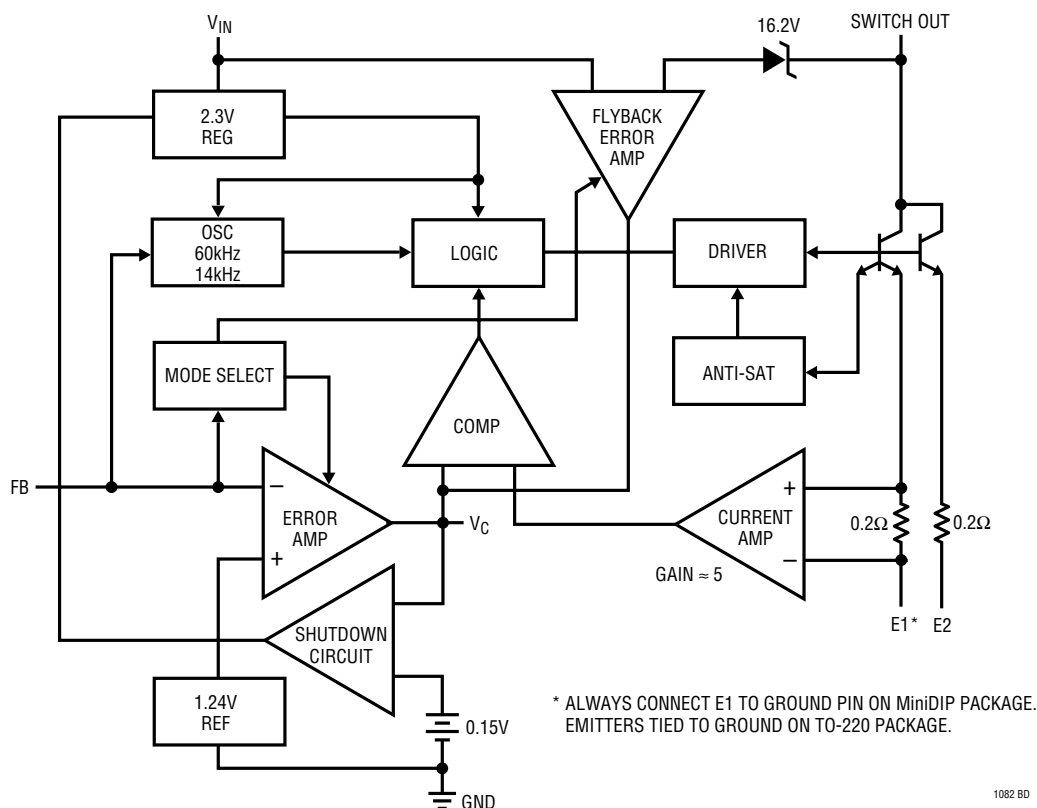
1082 G23

Transconductance of Error Amplifier



1082 G24

BLOCK DIAGRAM



OPERATION

The LT1082 is a current mode switch. This means that switch duty cycle is directly controlled by switch current rather than by output voltage. Referring to the block diagram, the switch is turned “on” at the start of each oscillator cycle. It is turned “off” when switch current reaches a predetermined level. Control of output voltage is obtained by using the output of a voltage sensing error amplifier to set current trip level. This technique has several advantages. First, it has immediate response to input voltage variations, unlike ordinary switchers which have notoriously poor line transient response. Second, it reduces the 90° phase shift at mid-frequencies in the energy storage inductor. This greatly simplifies closed-loop frequency compensation under widely varying input voltage or output load conditions. Finally, it allows simple pulse-by-pulse current limiting to provide maximum switch protection under output overload or short conditions. A

low dropout internal regulator provides a 2.3V supply for all internal circuitry on the LT1082. This low dropout design allows input voltage to vary from 3V to 75V with virtually no change in device performance. A 60kHz oscillator is the basic clock for all internal timing. It turns “on” the output switch via the logic and driver circuitry. Special adaptive anti-sat circuitry detects onset of saturation in the power switch and adjusts driver current instantaneously to limit switch saturation. This minimizes driver dissipation and provides very rapid turn-off of the switch.

A 1.2V bandgap reference biases the positive input of the error amplifier. The negative input is brought out for output voltage sensing. This feedback pin has a second function: when pulled low with an external resistor and with I_{FB} of 60μA to 200μA, it programs the LT1082 to

OPERATION

disconnect the main error amplifier output and connects the output of the flyback amplifier to the comparator input. The LT1082 will then regulate the value of the flyback pulse with respect to the supply voltage. This flyback pulse is directly proportional to output voltage in the traditional transformer coupled flyback topology regulator. By regulating the amplitude of the flyback pulse, the output voltage can be regulated with no direct connection between input and output. The output is fully floating up to the breakdown voltage of the transformer windings. Multiple floating outputs are easily obtained with additional windings. A special delay network inside the LT1082 ignores the leakage inductance spike at the leading edge of the flyback pulse to improve output regulation.

When I_{FB} drawn out of the FB pin reaches 350 μ A, the LT1082 shifts the switching frequency down to 12kHz. This unique feature provides high voltage short-circuit protection in systems like the telecom 5V supplies with input voltages down to -70V; lower frequency is needed under short-circuit conditions with current mode switchers because minimum “on” time cannot be forced below the internally set blanking time. Referring to the telecom 5V supply circuit on the front page, with output shorted to ground, the V_{FB} stays at 0.6V when sourcing I_{FB} up to 1mA. If the FB pin is forced to source more than 1mA, the frequency shifting function may be defeated. Therefore, the minimum suggested value for R_{FB} is 1k and the maximum suggested value is 1.2k. Also, no capacitance more than 1nF should be used on the FB pin, because it may cause unstable switching frequency in this low frequency mode.

The error signal developed at the comparator input is brought out externally. This pin (V_C) has four different functions. It is used for frequency compensation, current limit adjustment, soft starting, and total regulator shutdown. During normal regulator operation this pin sits at a voltage between 0.9V (low output current) and 2V (high output current). The error amplifiers are current output (g_m) types, so this voltage can be externally clamped for adjusting current limit. Likewise, a capacitor-coupled external clamp will provide soft start. Switch duty cycle goes to zero if the V_C pin is pulled to ground through a diode, placing the LT1082 in an idle mode. Pulling the V_C pin below 0.15V causes total regulator shutdown, with

only 120 μ A supply current for shutdown circuitry biasing. See AN19 for full application details.

Extra Pins on the MiniDIP Packages

The miniDIP LT1082 has the emitters of the power transistor brought out separately from the ground pin. This eliminates errors due to ground pin voltage drops and allows the user to reduce switch current limit by a factor of 2:1 by leaving the second emitter (E2) disconnected. The first emitter (E1) should always be connected to the ground pin. Note that switch “on” resistance doubles when E2 is left open, so efficiency will suffer somewhat when switch currents exceed 100mA. Also, note that chip dissipation will actually *increase* with E2 open during normal load operation, even though dissipation in current limit mode will *decrease*. See “Thermal Considerations.”

Thermal Considerations When Using the MiniDIP Packages

The low supply current and high switch efficiency of the LT1082 allow it to be used without a heat sink in most applications when the TO-220 package is selected.

This package is rated at 50°C/W. The miniDIPs, however, are rated at 100°C/W in ceramic (J) and 90°C/W in plastic (N).

Care should be taken for miniDIP applications to ensure that the worst case input voltage and load current conditions do not cause excessive die temperatures. The following formulas can be used as a rough guide to calculate LT1082 power dissipation. For more details, the reader is referred to Application Note 19 (AN19), “Efficiency Calculations” section.

Average supply current (including driver current) is:

$$I_{IN} \approx 4.5\text{mA} + I_{SW} (0.004 + \text{DC}/28)$$

I_{SW} = switch current

DC = switch duty cycle

Switch power dissipation is given by:

$$P_{SW} = (I_{SW})^2 \cdot R_{SW} \cdot \text{DC}$$

R_{SW} = LT1082 switch “on” resistance (1.2 Ω maximum)

OPERATION

Total power dissipation is the sum of supply current times input voltage plus switch power:

$$P_{TOT} = (I_{IN})(V_{IN}) + P_{SW}$$

In a typical example, using negative-to-positive converter to generate 5V at 0.5A from a -45V input, duty cycle is approximately 12%, and switch current is about 0.5A, yielding:

$$I_{IN} = 4.5\text{mA} + 0.5(0.004 + DC/28) = 8.7\text{mA}$$

$$P_{SW} = (0.5)^2 \cdot 1.2\Omega \cdot (0.12) = 0.036\text{W}$$

$$P_{TOT} = (45\text{V})(8.7\text{mA}) + 0.036 = 0.43\text{W}$$

Temperature rise in a plastic miniDIP would be 90°C/W times 0.43W, or approximately 39°C. The maximum ambient temperature would be limited to 100°C (commercial temperature limit) minus 39°C, or 61°C.

In most applications, full load current is used to calculate die temperature. However, if overload conditions must also be accounted for, four approaches are possible. First, if loss of regulated output is acceptable under overload conditions, the internal *thermal limit* of the LT1082 will protect the die in most applications by shutting off switch current. *Thermal limit* is not a tested parameter, however, and should be considered only for noncritical applications with temporary overloads. A second approach is to use the larger TO-220 (T) package which, even without a heat sink, may limit die temperatures to safe levels under overload conditions. In critical situations, heat sinking of these packages is required; especially if overload conditions must be tolerated for extended periods of time.

The third approach for lower current applications is to leave the second switch emitter (miniDIP only) open. This increases switch “on” resistance by 2:1, but reduces switch current limit by 2:1 also, resulting in a net 2:1 reduction in I^2R switch dissipation under current limit conditions.

The fourth approach is to clamp the V_C pin to a voltage less than its internal clamp level of 2V. The LT1082 switch current limit is zero at approximately 1V on the V_C pin and 1.6A at 2V on the V_C pin. Peak switch current can be externally clamped between these two levels with a diode. See AN19 for details.

LT1082 Synchronizing

The LT1082 can be externally synchronized in the frequency range of 75kHz to 90kHz. This is accomplished as shown in the accompanying figures. Synchronizing occurs when the V_C pin is pulled to ground with an external transistor. To avoid disturbing the DC characteristics of the internal error amplifier, the width of the synchronizing pulse should be under 1μs. C2 sets the pulse width at ≈ 0.6μs. The effect of a synchronizing pulse on the LT1082 amplifier offset can be calculated from:

$$\Delta V_{OS} = \frac{\left(\frac{KT}{q}\right)(t_s)(f_s)\left(I_C + \frac{V_C}{R3}\right)}{I_C}$$

$KT/q = 26\text{mV}$ at 25°C

t_s = pulse width

f_s = pulse frequency

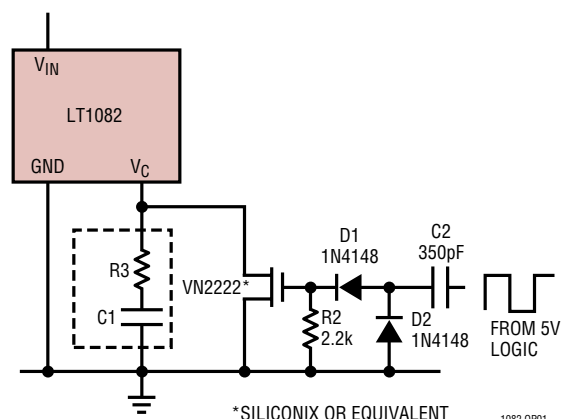
I_C = LT1082 V_C source current (≈ 200μA)

V_C = LT1082 operating V_C voltage (1V to 2V)

$R3$ = resistor used to set mid-frequency “zero” in LT1082 frequency compensation network.

With $t_s = 0.6\mu\text{s}$, $f_s = 80\text{kHz}$, $V_C = 1.5\text{V}$, and $R3 = 2\text{k}$, offset voltage shift is ≈ 5mV. This is not particularly bothersome, but note that high offset could result if $R3$ were reduced to a much lower value. Also, the synchronizing transistor must sink higher currents with low values of $R3$, so larger drives may have to be used. The transistor must be capable of pulling the V_C pin to within 100mV of ground to ensure synchronizing.

Synchronizing the LT1082

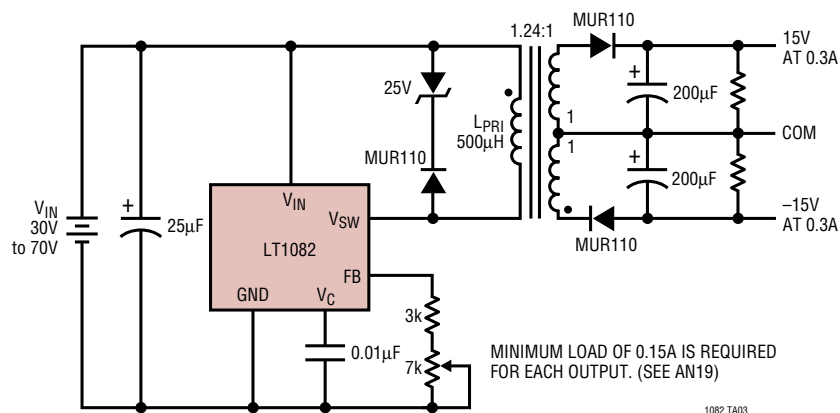


1082 OP01

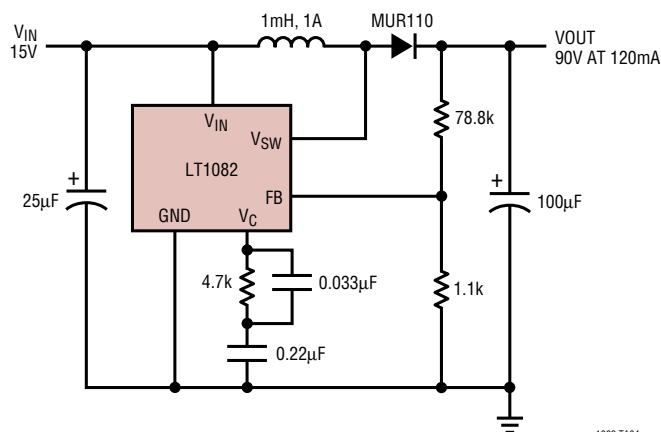
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TYPICAL APPLICATIONS

Totally Isolated Converter

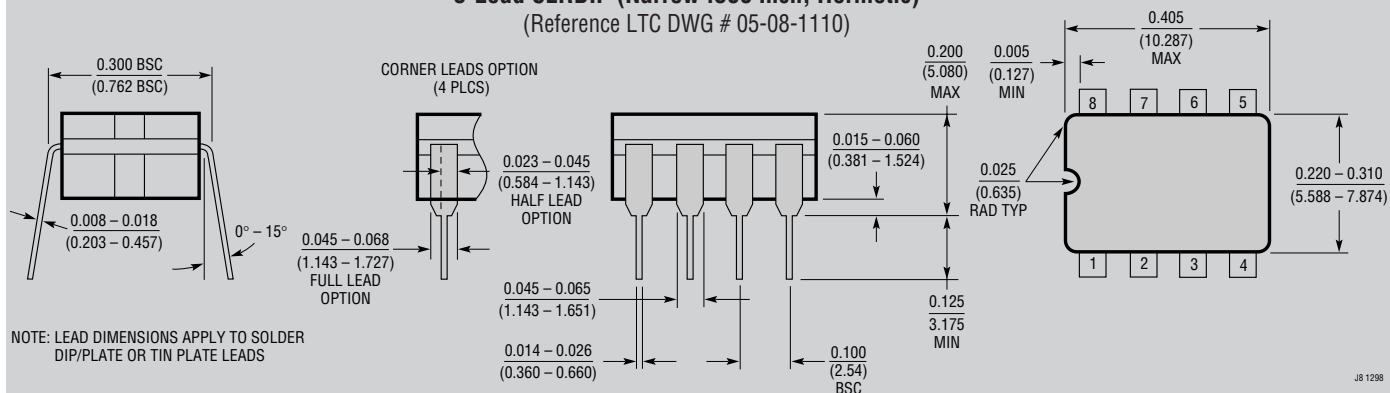


Boost Converter



PACKAGE DESCRIPTION

J8 Package
8-Lead CERDIP (Narrow .300 Inch, Hermetic)
 (Reference LTC DWG # 05-08-1110)

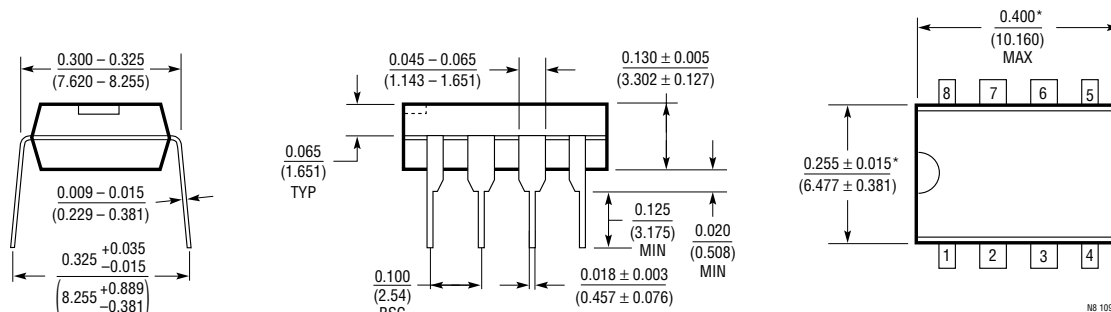


OBSOLETE PACKAGE

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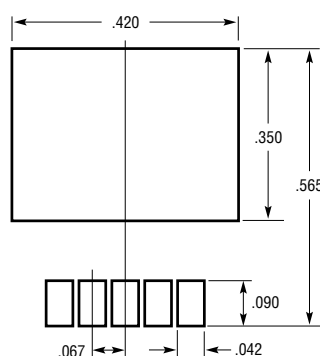
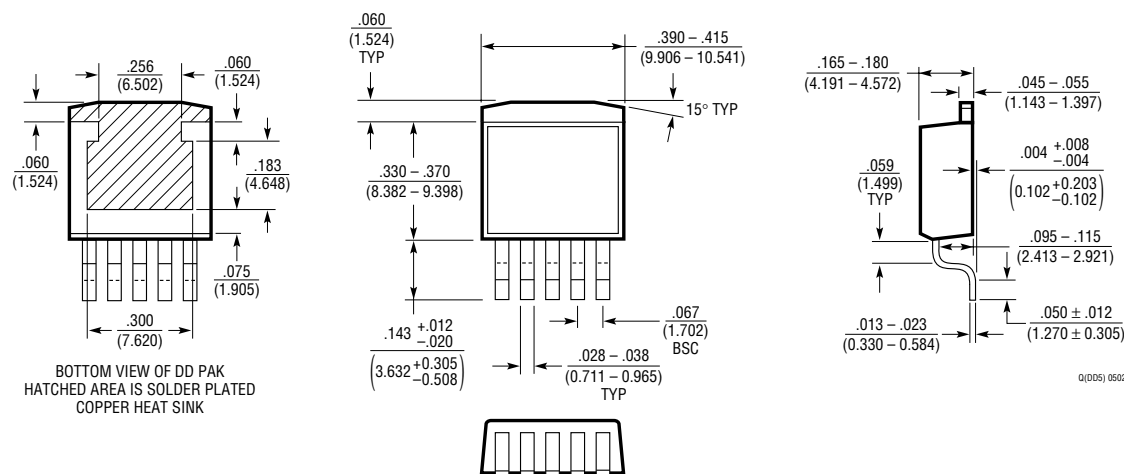
PACKAGE DESCRIPTION

N8 Package 8-Lead PDIP (Narrow .300 Inch) (Reference LTC DWG # 05-08-1510)

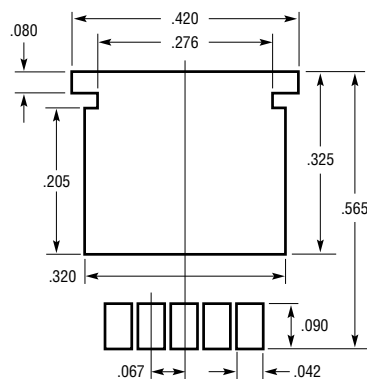


*THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS.
MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.010 INCH (0.254mm)

Q Package 5-Lead Plastic DD Pak (Reference LTC DWG # 05-08-1461)



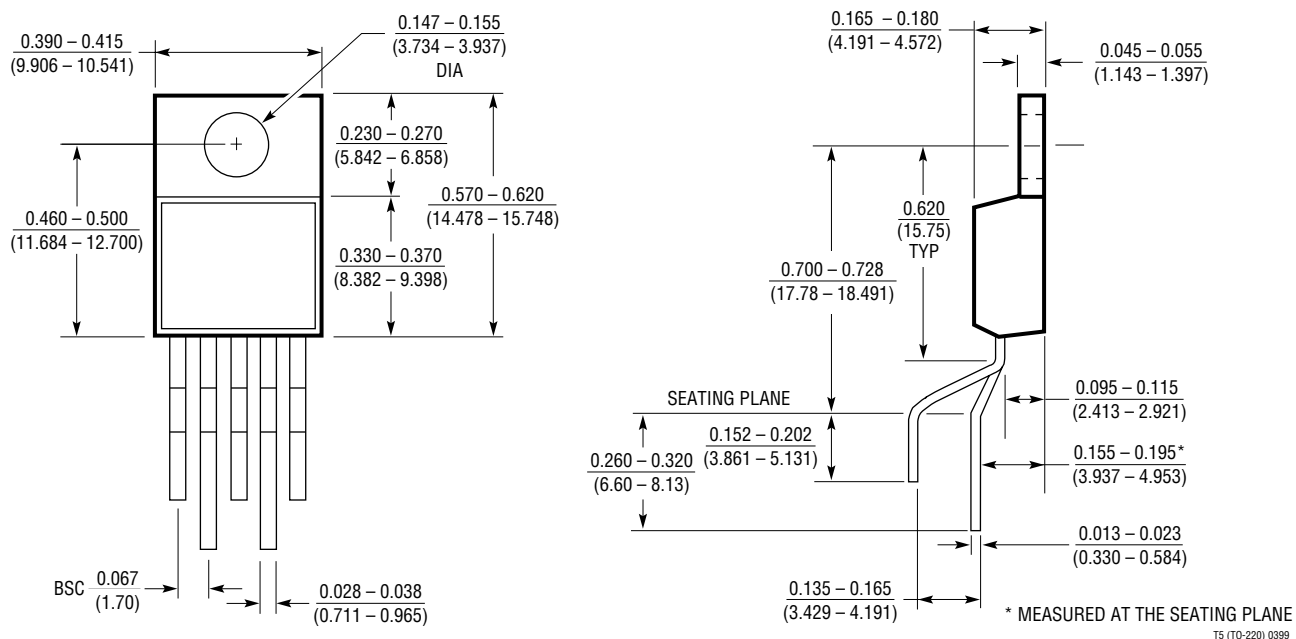
RECOMMENDED SOLDER PAD LAYOUT
NOTE:
1. DIMENSIONS IN INCH/(MILLIMETER)
2. DRAWING NOT TO SCALE



RECOMMENDED SOLDER PAD LAYOUT
FOR THICKER SOLDER PASTE APPLICATIONS

PACKAGE DESCRIPTION

T Package
5-Lead Plastic TO-220 (Standard)
 (Reference LTC DWG # 05-08-1421)



RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LT1765	1.25MHz, 3A, Step-Down Regulator	V_{IN} : 3V to 25V, V_{REF} = 1.2V, S08 Package
LT1767	1.25MHz, 1.25A, Step-Down Regulator	V_{IN} : 3V to 25V, V_{REF} = 1.2V, MSOP-8 Package
LTC3401	3MHz, 1A, Step-Up Regulator	V_{IN} : 0.5V to 5V, MSOP-10 Package
LTC3404	1.4MHz, I_{OUT} = 600mA, Step-Down Regulator	V_{IN} : 2.65V to 6V, V_{REF} = 0.8V, MSOP-8 Package
LTC3411	2MHz, 1.25A, Step-Down Regulator	V_{IN} : 2.5V to 5.5V, V_{REF} = 0.8V, MSOP-10, TSSOP-16E Package